2SB0621A

Silicon PNP epitaxial planar type

For low-frequency driver amplification
Complementary to 2SD0592A

■ Features

- Low collector-emitter saturation voltage $V_{CE(sat)}$
- High transition frequency f_T

■ Package

- Code
  TO-92B-B1
- Pin Name
  1. Emitter
  2. Collector
  3. Base

■ Absolute Maximum Ratings $T_a = 25°C$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	–60	V
Collector-emitter voltage (Base open)	V_{CEO}	–50	V
Emitter-base voltage (Collector open)	V_{EBO}	–5	V
Collector current	I_C	–1	A
Peak collector current	I_{CP}	–1.5	A
Collector power dissipation	P_C	750	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	–55 to +150	°C

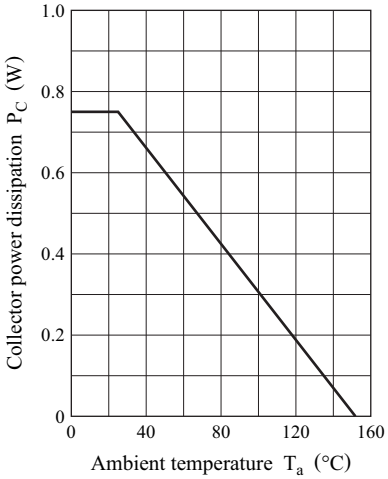
■ Electrical Characteristics $T_a = 25°C \pm 3°C$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	V_{CBO}	$I_C = –10\ \mu A$, $I_E = 0$	–60			V
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = –2$ mA, $I_B = 0$	–50			V
Emitter-base voltage (Collector open)	V_{EBO}	$I_E = –10\ \mu A$, $I_C = 0$	–5			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = –20$ V, $I_E = 0$			– 0.1	μA
Forward current transfer ratio	h_{FE1} *	$V_{CE} = –10$ V, $I_C = –500$ mA	85		340	—
	h_{FE2}	$V_{CE} = –5$ V, $I_C = –1$ A	50			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = –500$ mA, $I_B = –50$ mA		– 0.2	– 0.4	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = –500$ mA, $I_B = –50$ mA		– 0.85	–1.2	V
Transition frequency	f_T	$V_{CB} = –10$ V, $I_E = 50$ mA, f = 200 MHz		200		MHz
Collector output capacitance (Common base, input open circuited)	C_{ob}	$V_{CB} = –10$ V, $I_E = 0$, f = 1 MHz		20	30	pF

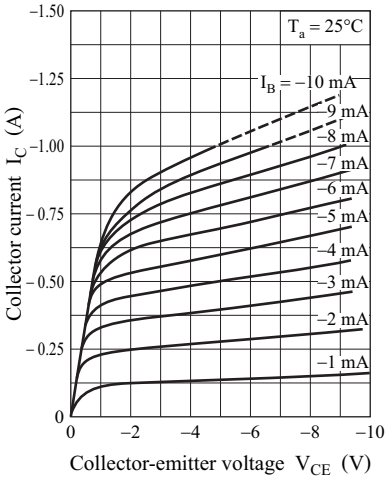
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.
2. *: Rank classification

Rank	Q	R	S
h_{FE1}	85 to 170	120 to 240	170 to 340

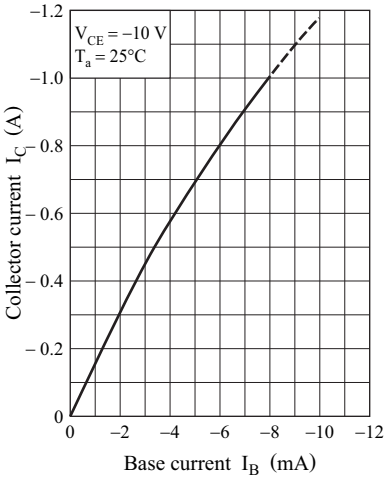
P_C — T_a



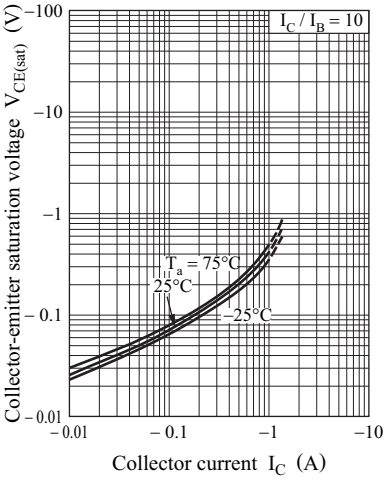
I_C — V_{CE}



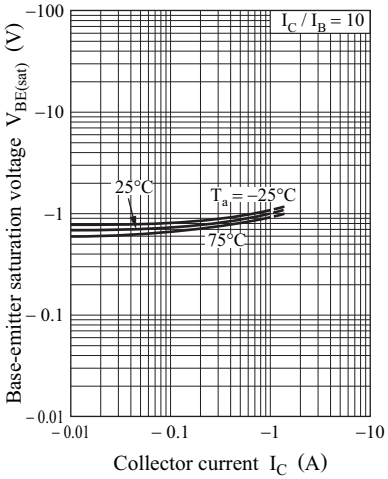
I_C — I_B



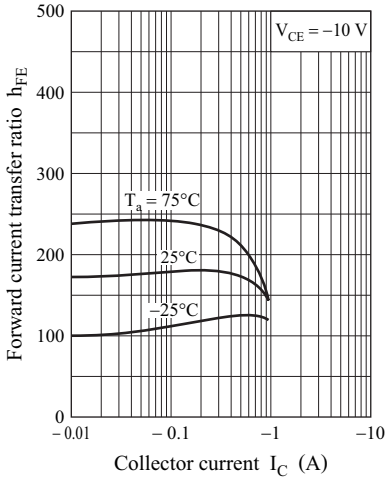
$V_{CE(sat)}$ — I_C



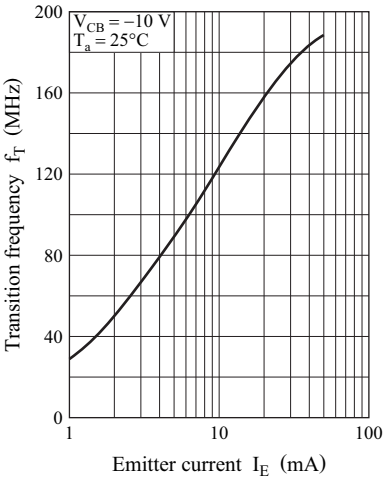
$V_{BE(sat)}$ — I_C



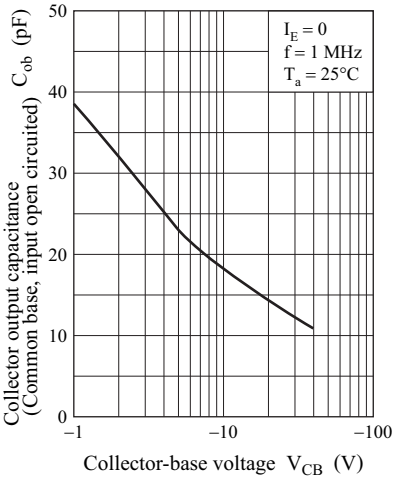
h_{FE} — I_C



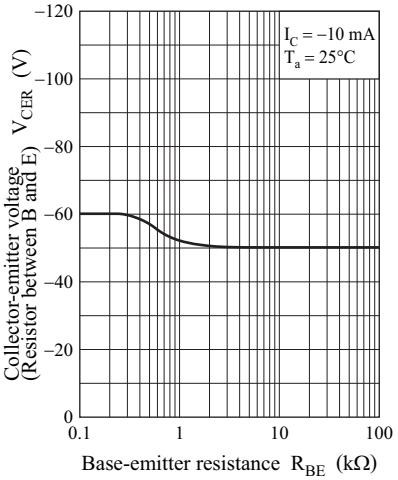
f_T — I_E



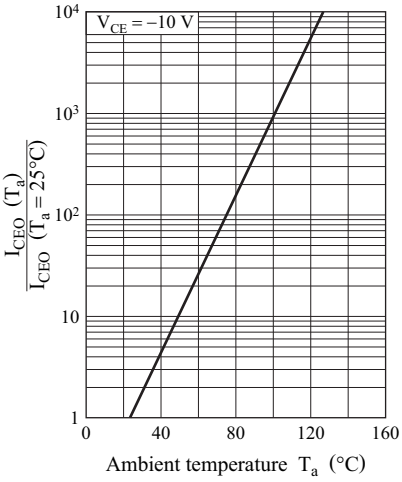
C_{ob} — V_{CB}



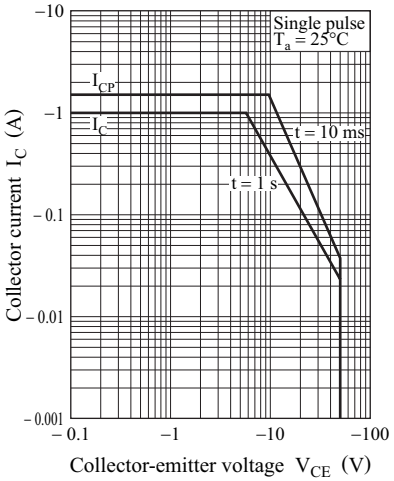
V_{CER} — R_{BE}



I_{CEO} — T_a

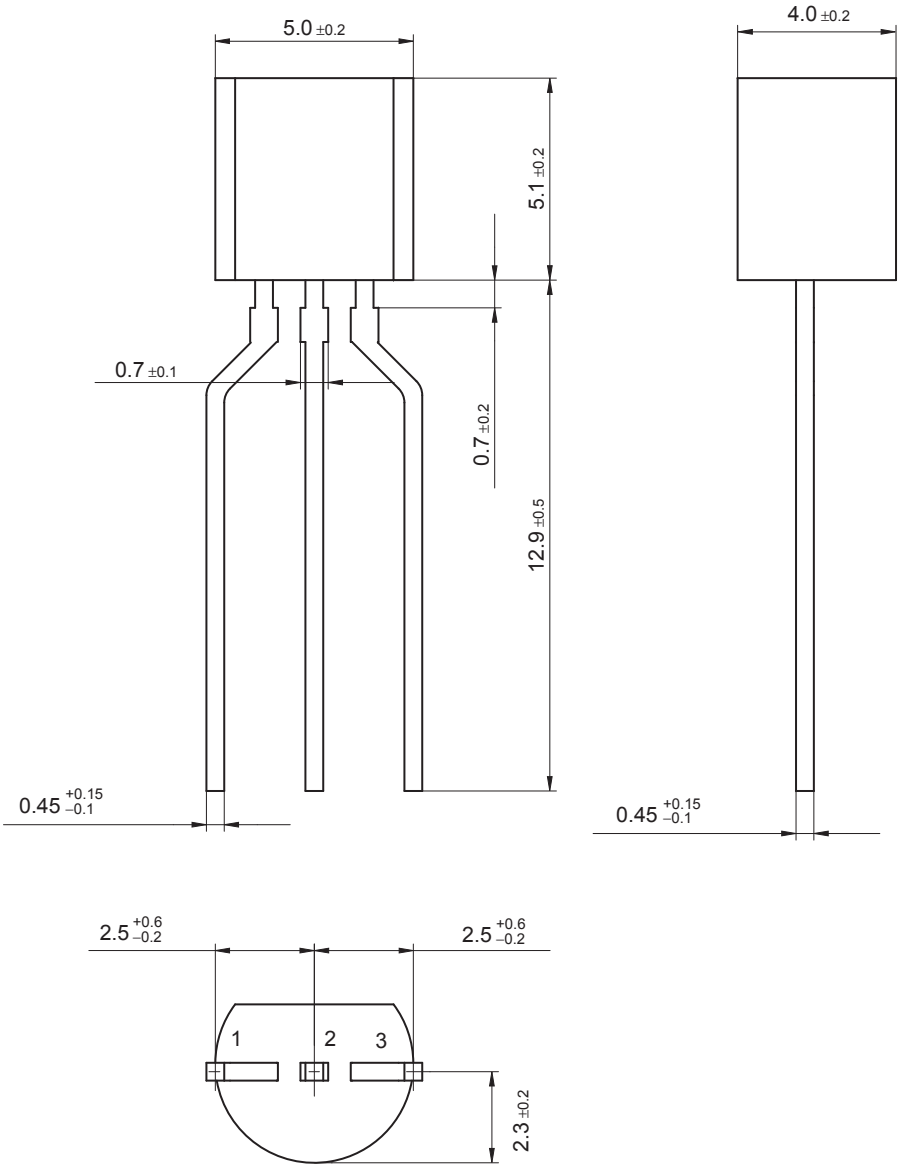


安全動作領域



TO-92-B1

Unit: mm



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